

# MUR1520PbF

## **Ultrafast Rectifier**

#### **Features**

- · Ultrafast Recovery Time
- · Low Forward Voltage Drop
- · Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

 $t_{rr}$  = 35ns  $I_{F(AV)}$  = 15Amp  $V_R$  = 200V

#### **Description/ Applications**

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

#### **Absolute Maximum Ratings**

	Parameters	Max	Units
$V_{RRM}$	Peak Repetitive Peak Reverse Voltage	200	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	15	A
	Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C		
I <sub>FSM</sub>	Non Repetitive Peak Surge Current	200	
I <sub>FM</sub>	Peak Repetitive Forward Current	30	
	(Rated $V_R$ , Square wave, 20 KHz), $T_C = 150$ °C		
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperatures	-65 to 175	°C



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# Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Мах	Units	Test Conditions
$V_{BR}, V_{r}$	Breakdown Voltage, Blocking Voltage	200	-	-	V	Ι <sub>R</sub> = 100μΑ
V <sub>F</sub>	Forward Voltage	-	-	1.05	V	I <sub>F</sub> = 15A
		-	-	0.85	V	I <sub>F</sub> = 15A, T <sub>J</sub> = 150°C
I <sub>R</sub>	Reverse Leakage Current	-	-	10	μA	$V_R = V_R$ Rated
		-	-	500	μA	$T_J = 150$ °C, $V_R = V_R$ Rated
Ст	Junction Capacitance	-	55	-	pF	V <sub>R</sub> = 200V
L <sub>S</sub>	Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

## Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

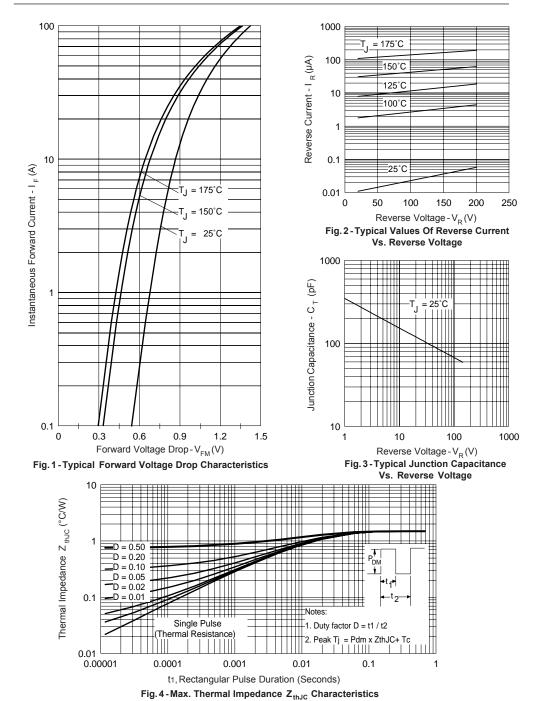
	Parameters	Min	Тур	Max	Units	Test Condition	s		
t <sub>rr</sub>	Reverse Recovery Time	-	-	35	ns	I <sub>F</sub> = 1.0A, di <sub>F</sub> /dt =	$0A, di_F/dt = 50A/\mu s, V_R = 30V$		
		-	22	-		T <sub>J</sub> = 25°C	I <sub>F</sub> = 15A		
		-	39	-		T <sub>J</sub> = 125°C	V <sub>R</sub> = 160V		
I <sub>RRM</sub>	Peak Recovery Current	-	1.6	-	Α	T <sub>J</sub> = 25°C	di <sub>F</sub> /dt = 200A/µs		
		-	4.1	-		T <sub>J</sub> = 125°C			
Q <sub>rr</sub>	Reverse Recovery Charge	-	19	-	nC	T <sub>J</sub> = 25°C			
		-	90	-		T <sub>J</sub> = 125°C			

## **Thermal - Mechanical Characteristics**

	Parameters	Min	Тур	Max	Units
TJ	Max. Junction Temperature Range	- 65	-	175	°C
T <sub>Stg</sub>	Max. Storage Temperature Range	- 65	-	175	
R <sub>thJC</sub>	Thermal Resistance, Junction to Case	-	-	1.5	°C/ W
R <sub>thJA</sub>	Thermal Resistance, Junction to Ambient	-	-	50	
R <sub>thCS</sub> ①	Thermal Resistance, Case to Heatsink	-	0.5	-	
Wt	Weight	-	2.0	-	g
		-	0.07	-	(oz)
	Mounting Torque	6.0	-	12	Kg-cm
		5.0	-	10	lbf.in
	Marking Device	MUR1520			

① Mounting Surface, Flat, Smooth and Greased

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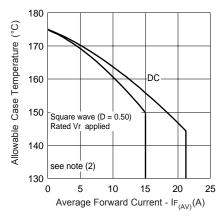


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

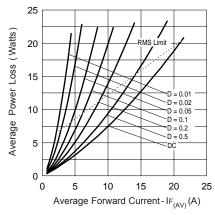


Fig. 6-Forward Power Loss Characteristics

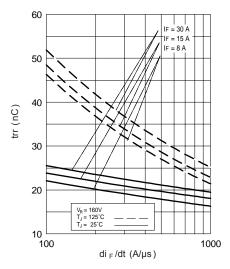


Fig. 7 - Typical Reverse Recovery vs. di  $_{\rm F}$  /dt

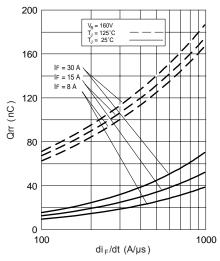


Fig. 8 - Typical Stored Charge vs.  $di_F/dt$ 

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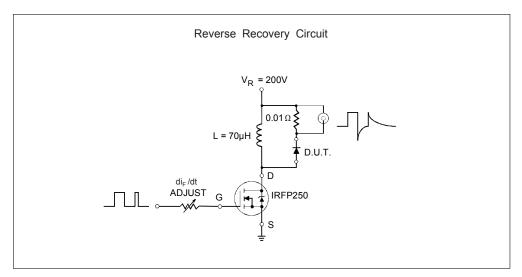


Fig. 9- Reverse Recovery Parameter Test Circuit

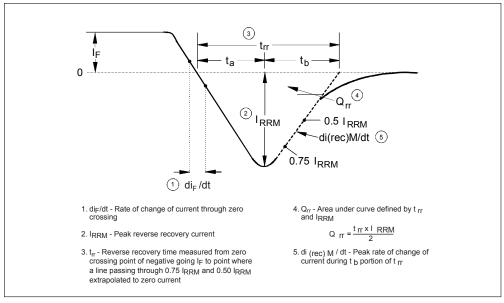
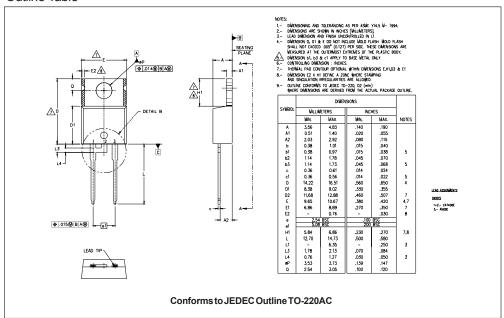


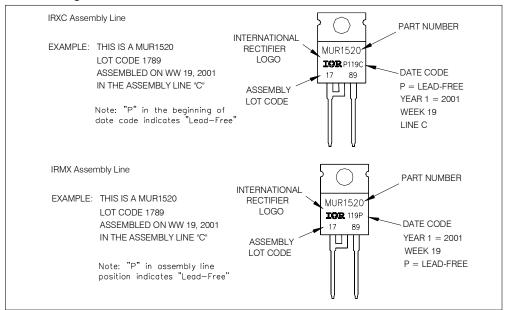
Fig. 10 - Reverse Recovery Waveform and Definitions

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#### **Outline Table**

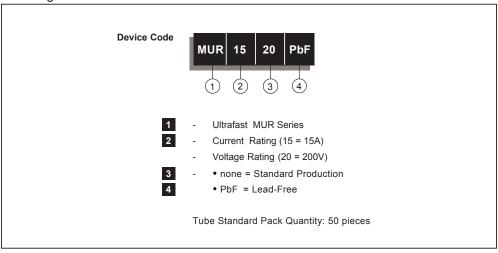


### Part Marking Information



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### Ordering Information Table



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MUR1520
* SPICE Model Diode
.SUBCKT MUR1520 ANO CAT
D1 ANO 1 CAT
*Define diode model
.MODEL DMOD D Is=16.9E-09 N=1.332 Rs=4.439E-03 lkf=.232 Xti=2 Eg=1.11
              Cjo=700.3E-09M=.3715Vj=.1784Fc=.5Isr=1.389E-09
              Nr=3.002Bv=270lbv=95.79E-6Tt=10.49E-9)
************
.ENDS MUR1520
Thermal Model Subcircuit
.SUBCKT MUR1520 51
CTHERM1
                       2.23E+01
                       1.23E+02
CTHERM2
                3
CTHERM3
                       3.35E+02
CTHERM4
                       4.75E+02
RTHERM1
                       7.55E-01
RTHERM2
           4
                       5.90E-02
                3
RTHERM1
            3
                       1.01E-01
RTHERM1
                       5.43E-02
.ENDS MUR1520
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Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free.

Qualification Standards can be found on IR's Web site.

# International IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309 02/06

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